650V , RDS(ON) = $78m\Omega(max)$, ID = 39A N-Channel SiC power MOSFET

Features:

- Easy to parallel
- Fast switching speed
- Fast reverse recovery
- Low on-resistance
- Pb-free lead plating ; RoHS compliant
- Simple to drive

Applications:

- DC/DC converters
- Induction heating
- Motor drives
- Solar inverters
- Switch mode power supplies





